

■ 100% UIL tested

FAIRCHILD

RoHS Compliant

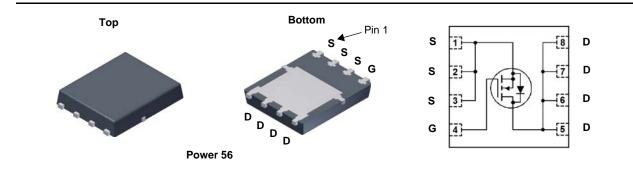


General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench[®] process that has been especially tailored to minimize the on-state resistance and yet maintain superior switching performance.

Application

DC-DC Conversion



MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			150	V	
V _{GS}	Gate to Source Voltage			±20	V	
	Drain Current -Continuous (Package limited)	T _C = 25 °C		20		
,	-Continuous (Silicon limited)	T _C = 25 °C		42	Α	
D	-Continuous	T _A = 25 °C	(Note 1a)	6.7	A	
	-Pulsed			50		
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	180	mJ	
D	Power Dissipation	T _C = 25 °C		96	w	
P _D	Power Dissipation	T _A = 25 °C	(Note 1a)	2.5	vv	
T _J , T _{STG}	Operating and Storage Junction Temperature R	ange		-55 to +150	°C	

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	1.3	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient (Note 1a)	50	C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS86250	FDMS86250	Power 56	13 "	12 mm	3000 units

©2011 Fairchild Semiconductor Corporation FDMS86250 Rev. C

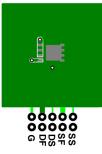
1

December 2011

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	150			V
ΔBV_{DSS} ΔT_J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		106		mV/°C
IDSS	Zero Gate Voltage Drain Current	V _{DS} = 120 V, V _{GS} = 0 V			1	μA
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20 V, V_{DS} = 0 V$			±100	nA
On Chara	cteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250 μA	2.0	2.9	4.0	V
$\Delta V_{GS(th)}$ $\Delta T_{.1}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-11		mV/°C
		V _{GS} = 10 V, I _D = 6.7 A		19	25	mΩ
r _{DS(on)}	Static Drain to Source On Resistance	$V_{GS} = 6 \text{ V}, I_D = 5.8 \text{ A}$		23	33	
- (-)		V _{GS} = 10 V, I _D = 6.7 A, T _J = 125 °C		35	46	
9 _{FS}	Forward Transconductance	V _{DS} = 10 V, I _D = 6.7 A		24		S
C _{iss} C _{oss}	Input Capacitance Output Capacitance Deverse Transfer Capacitance	V _{DS} = 75 V, V _{GS} = 0 V, f = 1 MHz		1750 165	2330 220	pF pF
C _{rss}	Reverse Transfer Capacitance			8.8	15	pF
R _g	Gate Resistance			0.5		Ω
Switching	g Characteristics					
t _{d(on)}	Turn-On Delay Time			14	25	ns
t _r	Rise Time	V _{DD} = 75 V, I _D = 6.7 A,		4.3	10	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		22	35	ns
t _f	Fall Time			4.2	10	ns
Qg	Total Gate Charge	$V_{GS} = 0$ V to 10 V		25	36	nC
Q _g	Total Gate Charge	$V_{GS} = 0 V \text{ to } 5 V V_{DD} = 75 V,$		14	20	nC
Q _{gs}	Gate to Source Charge	I _D = 6.7 A		7.4		nC
Q _{gd}	Gate to Drain "Miller" Charge			5.5		nC
Drain-Soເ	urce Diode Characteristics					
		$V_{GS} = 0 V, I_S = 2 A$ (Note 2)		0.72	1.2	
V _{SD}	Source-Drain Diode Forward Voltage	$V_{ab} = 0 V I_{a} = 67 A \qquad (Note 2)$		0.78	13	V

$V_{GS} = 0 V, I_S = 2 A$ (Note 2)	0.72	1.2	V
$V_{GS} = 0 V, I_S = 6.7 A$ (Note 2)	0.78	1.3	v
L = 6.7 A di/dt = 100 A/wc	73	117	ns
$F = 0.7 \text{ A, u/u} = 100 \text{ A/}\mu\text{s}$	112	180	nC
		$V_{GS} = 0 \ V, \ I_S = 6.7 \ A \ (Note 2) \qquad 0.78$ $I_{\Gamma} = 6.7 \ A, \ di/dt = 100 \ A/\mu S \qquad 73$	$V_{GS} = 0$ $V_{IS} = 6.7$ A $(Note 2)$ 0.78 1.3 $I_{F} = 6.7$ A $didt = 100$ A/us 73 117

Notes: 1. $R_{\theta JA}$ is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. $R_{\theta JC}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.



2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0%.

3. Starting T_J = 25 °C, L = 1 mH, I_{AS} = 19 A, V_{DD} = 135 V, V_{GS} = 10 V.

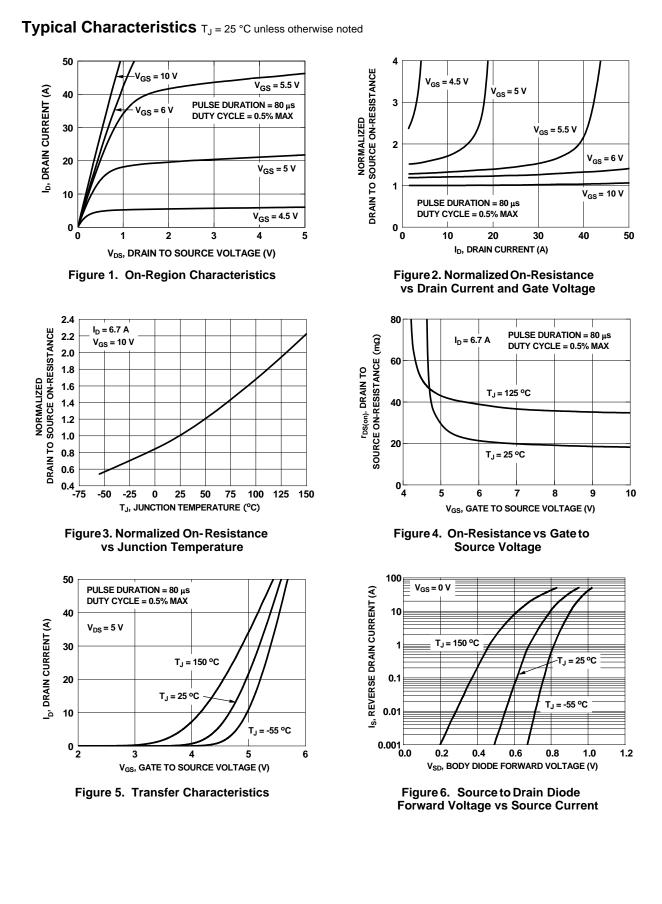
a. 50 °C/W when mounted on a 1 in² pad of 2 oz copper.



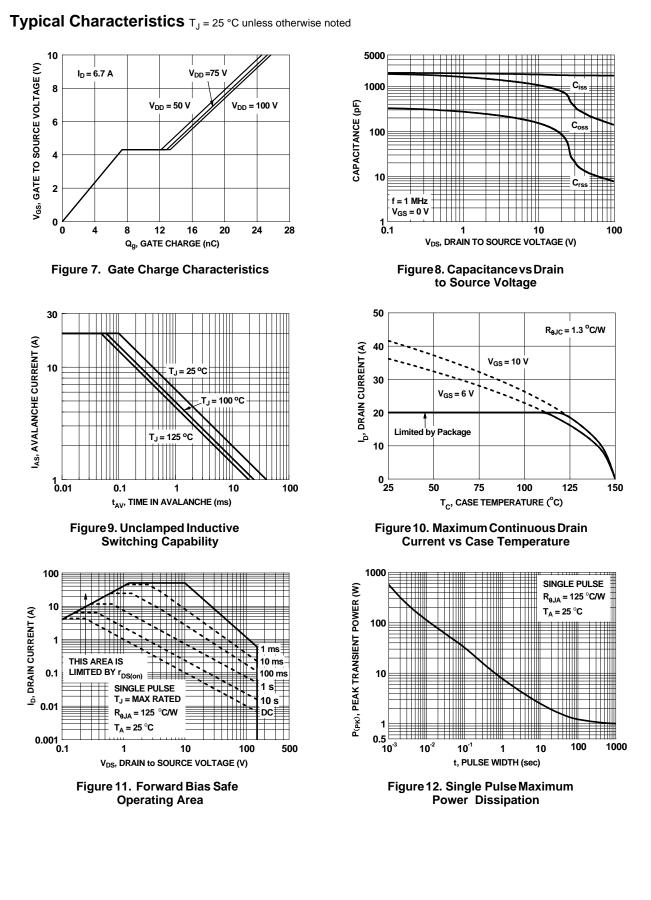
b. 125 °C/W when mounted on a minimum pad of 2 oz copper.

©2011 Fairchild Semiconductor Corporation FDMS86250 Rev. C

2

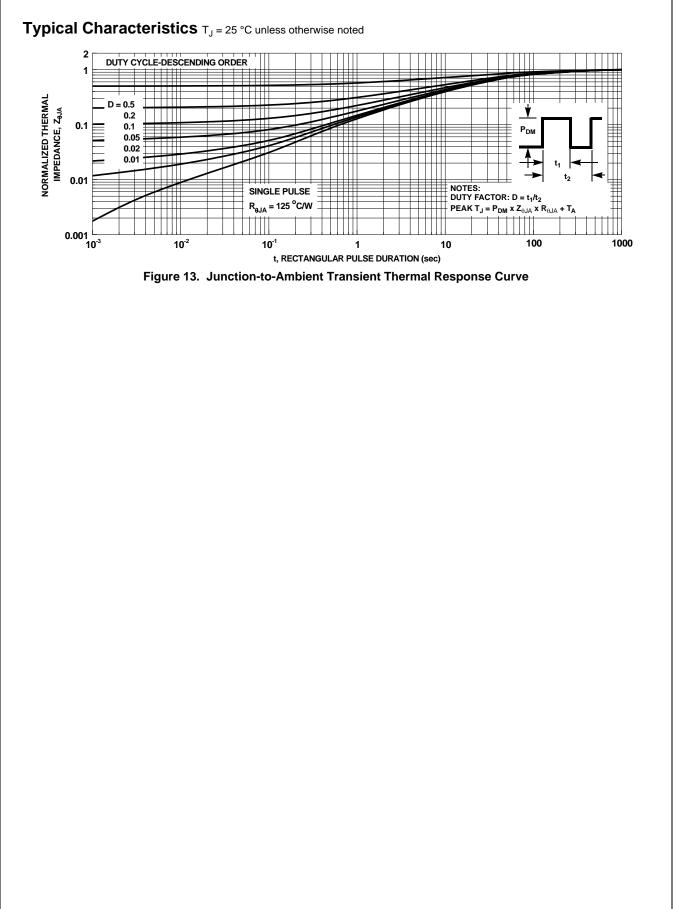


©2011 Fairchild Semiconductor Corporation FDMS86250 Rev. C



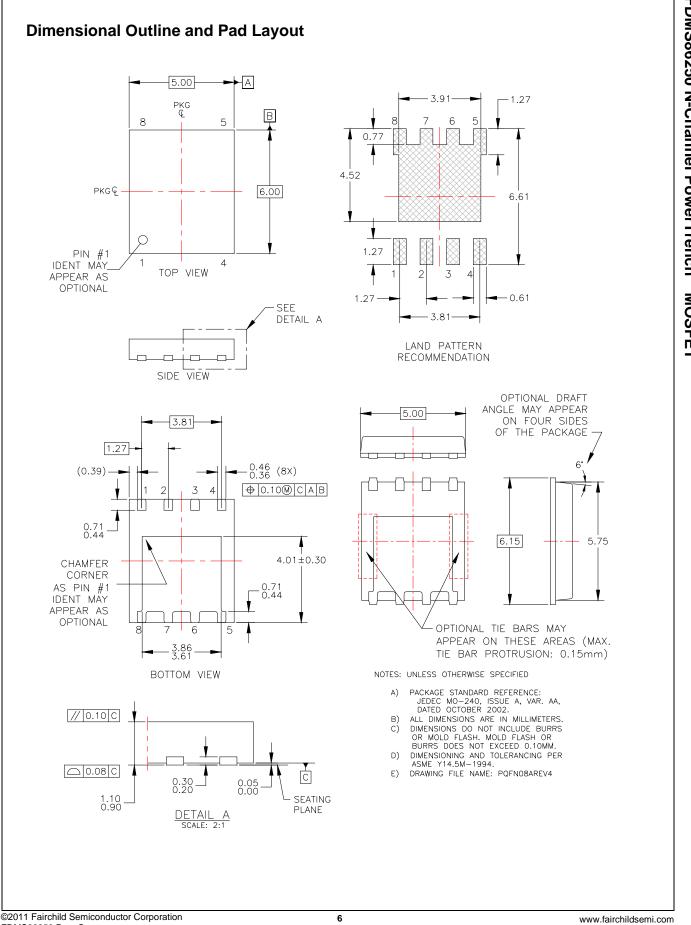
©2011 Fairchild Semiconductor Corporation FDMS86250 Rev. C

FDMS86250 N-Channel PowerTrench[®] MOSFET



©2011 Fairchild Semiconductor Corporation FDMS86250 Rev. C

FDMS86250 N-Channel PowerTrench[®] MOSFET



FDMS86250 N-Channel PowerTrench[®] MOSFET

FDMS86250 Rev. C



SEMICONDUCTOR

TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

2Cool™ AccuPower™ Auto-SPM™ AX-CAP™* BitSiC[®] Build it Now™ CorePLUS™ CorePOWER™ CROSSVOLT™ CTL™ Current Transfer Logic™ DEUXPEED® Dual Cool™ EcoSPARK® EfficentMax™ ESBC™

F Fairchild® Fairchild Semiconductor® FACT Quiet Series™ FACT FAST® FastvCore™ FETBench™ FlashWriter[®] *

FPS™ F-PFS™ **FRFET**® Global Power ResourceSM GreenBridge™ Green FPS™ Green FPS™ e-Series™ Gmax™ GTO™ IntelliMAX™ ISOPLANAR™ Marking Small Speakers Sound Louder and Better™ MegaBuck™ MICROCOUPLER™ MicroFET™ MicroPak™ MicroPak2™ MillerDrive™ MotionMax™ Motion-SPM™ mWSaver™ OptoHiT™ **OPTOLOGIC[®] OPTOPLANAR**[®]

R PowerTrench[®] PowerXS™ Programmable Active Droop™ QFET[®] QS™ Quiet Series™ RapidConfigure™ Saving our world, 1mW/W/kW at a time™ SignalWise™ SmartMax™ SMART START™ Solutions for Your Success™ SPM STEALTH™ SuperFET[®] SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS[®] SyncFET™

wer p franchise TinyBoost™ TinyBuck™ TinyCalc™ TinyLogic® TINYOPTO™ TinyPower™ TinyPWM™ TinyWire™ TranSiC[®] TriFault Detect™ TRUECURRENT®* µSerDes™ UHC® Ultra FRFET™ UniFET™

The Power Franchise[®]

VCX™ VisualMax™ VoltagePlus™ XS™

*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN, FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN. WHICH COVERS THESE PRODUCTS.

Sync-Lock™

GENERAL ®*

LIFE SUPPORT POLICY FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used here in:

- Life support devices or systems are devices or systems which, (a) are 1. intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.Fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufactures of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed application, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handing and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS **Definition of Terms**

Advance Information Formative / In Design Datasheet contains the design specifications for product development. Specifications Preliminary First Production Datasheet contains preliminary data; supplementary data will be published date. Fairchild Semiconductor reserves the right to make changes at any time vithout notice. No Identification Needed Full Production Datasheet contains final specifications. Fairchild Semiconductor reserves the reserves the design.	Definition	Product Status	Datasheet Identification
Preliminary First Production date. Fairchild Semiconductor reserves the right to make changes at any til notice to improve design. No Identification Needed Full Production Datasheet contains final specifications. Fairchild Semiconductor reserves the make changes at any time without notice to improve the design.	gn specifications for product development. Specifications without notice.	Formative / In Design	Advance Information
make changes at any time without notice to improve the design.	ary data; supplementary data will be published at a later or reserves the right to make changes at any time without	First Production	Preliminary
		Full Production	No Identification Needed
Obsolete Not In Production Datasheet contains specifications on a product that is discontinued by Faire Semiconductor. The datasheet is for reference information only.	ations on a product that is discontinued by Fairchild set is for reference information only.	Not In Production	Obsolete

FDMS86250 Rev. C Downloaded from Elcodis.com electronic components distributor